



ELECTRONICS, INC.  
 44 FARRAND STREET  
 BLOOMFIELD, NJ 07003  
 (973) 748-5089  
<http://www.nteinc.com>

## NTE703

### Linear Integrated Circuit

### RF-IF Amplifier

**Description:**

The NTE703 is an RF-IF amplifier intended for use as a limiting or non-limiting amplifier, harmonic mixer, or oscillator to 150MHz. The low internal feedback of the device insures a higher stability-limited gain.

**Features:**

- Few external components

**Absolute Maximum Ratings:**

Supply Voltage, V+	20V
Output Collector Voltage	24V
Voltage Between Input Pins	±5.0V
Internal Power Dissipation	500mW
Operating Temperature Range, T <sub>opr</sub>	0°C to +70°C
Storage Temperature Range, T <sub>stg</sub>	-65°C to +150°C
Lead Temperature (Soldering, 60 seconds), T <sub>L</sub>	300°C

**Electrical Characteristics:** (T<sub>A</sub> = 25°C, V+ = 12V unless otherwise specified)

Parameter	Test Conditions	Min	Typ	Max	Unit
Power Consumption	e <sub>in</sub> = 0	-	110	170	mW
Quiescent Output Current	e <sub>in</sub> = 0	1.5	2.5	3.3	mA
Peak-to-Peak Output Current	e <sub>in</sub> = 400mV <sub>rms</sub> , f = 1kHz	3.0	-	-	mA
Output Saturation Voltage		-	-	1.7	V
Forward Transadmittance	e <sub>in</sub> = 10mV <sub>rms</sub> , f = 1kHz	29	33	-	mmho
Input Conductance	e <sub>in</sub> < 10mV <sub>rms</sub> , f = 10.7MHz	-	0.35	1.0	mmho
Input Capacitance	e <sub>in</sub> < 10mV <sub>rms</sub> , f = 10.7MHz	-	9.0	12.5	pF
Output Capacitance	e <sub>o</sub> = 100mV <sub>rms</sub> , f = 10.7MHz	-	2.0	4.0	pF
Output Conductance	e <sub>o</sub> = 100mV <sub>rms</sub> , f = 10.7MHz	-	-	0.05	mmho
Noise Figure	f = 30MHz, R <sub>S</sub> = 500Ω	-	6.5	-	dB
	f = 100MHz, R <sub>S</sub> = 500Ω	-	8.0	-	

**Electrical Characteristics (Cont'd):** ( $T_A = 25^\circ\text{C}$ ,  $V_+ = 12\text{V}$  unless otherwise specified)

Parameter	Test Conditions	Min	Typ	Max	Unit
<b>The following specifications apply for <math>0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}</math></b>					
Quiescent Output Current	$e_{in} = 0$	1.7	-	3.5	mA
Peak-to-Peak Output Current	$e_{in} = 400\text{mV}_{\text{rms}}$ , $f = 1\text{kHz}$	3.2	-	-	mA
Output Saturation Voltage		-	-	1.8	V
Forward Transadmittance	$e_{in} = 10\text{mV}_{\text{rms}}$ , $f = 1\text{kHz}$	22	-	-	mmho
Input Conductance	$e_{in} < 10\text{mV}_{\text{rms}}$ , $f = 1\text{kHz}$	-	-	0.71	mmho
Output Conductance	$e_o = 100\text{mV}_{\text{rms}}$ , $f \leq 5\text{MHz}$	-	-	0.06	mmho

